

Pb Free Plating Product

## SFF1601G thru SFF1608G



16.0 Amperes Insulated Common Cathode Super Fast Recovery Rectifiers

### Features

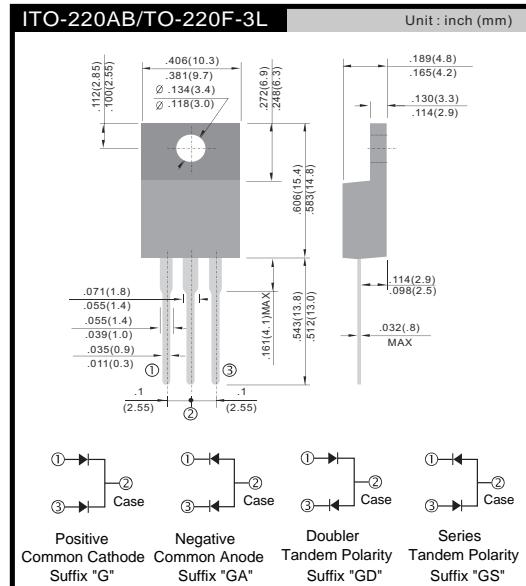
- \* Super fast switching for high efficiency
- \* Low forward voltage drop
- \* High current capability
- \* Low reverse leakage current
- \* High surge current capability

### Application

- \* Automotive Inverters and Solar Inverters
- \* Plating Power Supply, SMPS and UPS
- \* Car Audio Amplifiers and Sound Device Systems

### Mechanical Data

- \* Case: ITO-220AB full plastic isolated package
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Terminals: Solderable per MIL-STD-202 method 208
- \* Polarity: As marked on diode body
- \* Mounting position: Any
- \* Weight: 1.75 gram approximately



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	SFF 1601G	SFF 1602G	SFF 1603G	SFF 1604G	SFF 1605G	SFF 1606G	SFF 1607G	SFF 1608G	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	$V_{RMS}$	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current	$I_{F(AV)}$					16				A
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$					125				A
Maximum instantaneous forward voltage (Note 1) $I_F = 8 \text{ A}$	$V_F$			0.975		1.3		1.7		V
Maximum reverse current @ Rated $V_R$ $T_J=25^\circ\text{C}$ $T_J=125^\circ\text{C}$	$I_R$				10					$\mu\text{A}$
					400					
Maximum reverse recovery time (Note 2)	$T_{rr}$				35					ns
Typical junction capacitance (Note 3)	$C_J$		80			50				pF
Typical thermal resistance	$R_{\theta JC}$				3.0					$^\circ\text{C/W}$
Operating junction temperature range	$T_J$				- 55 to +150					$^\circ\text{C}$
Storage temperature range	$T_{STG}$				- 55 to +150					$^\circ\text{C}$

Note 1: Pulse Test with  $PW=300\mu\text{s}$ , 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions:  $I_F=0.5\text{A}$ ,  $I_R=1.0\text{A}$ ,  $I_{RR}=0.25\text{A}$ .

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

## RATINGS AND CHARACTERISTICS CURVES

(TA=25°C unless otherwise noted)

FIG.1 FORWARD CURRENT DERATING CURVE

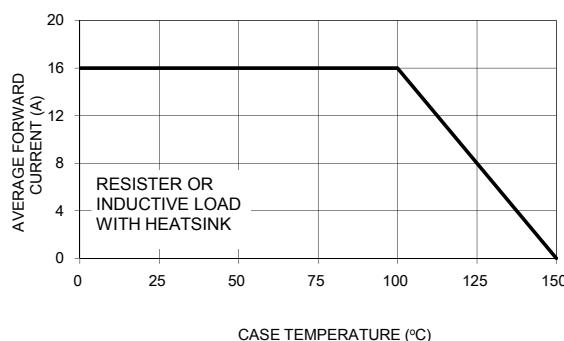


FIG. 2 TYPICAL REVERSE CHARACTERISTICS

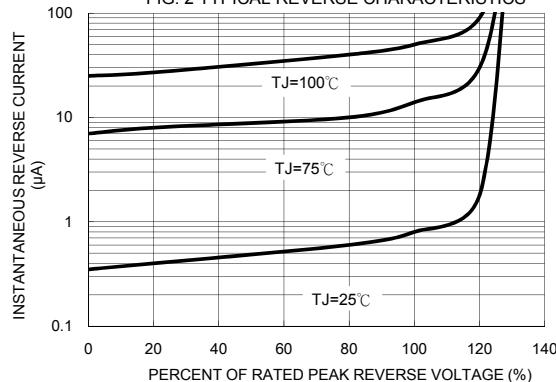


FIG. 3 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

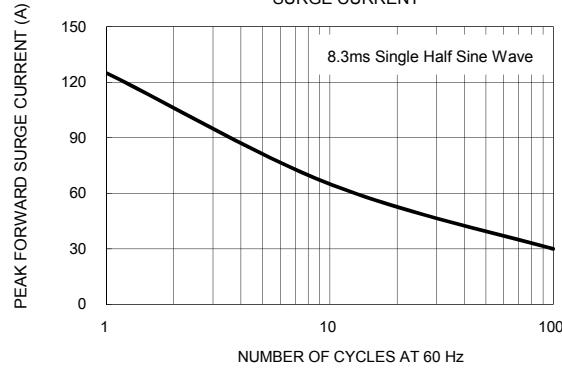


FIG. 4 TYPICAL FORWARD CHARACTERISTICS

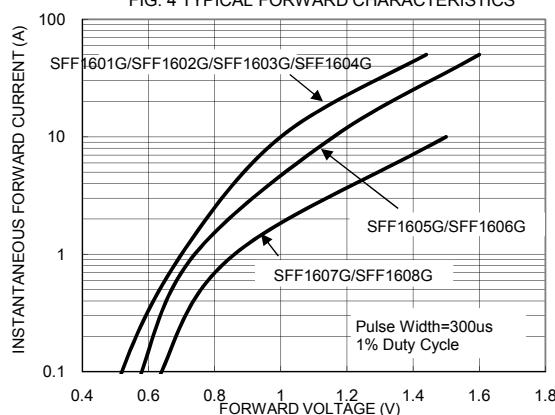


FIG. 5 TYPICAL JUNCTION CAPACITANCE

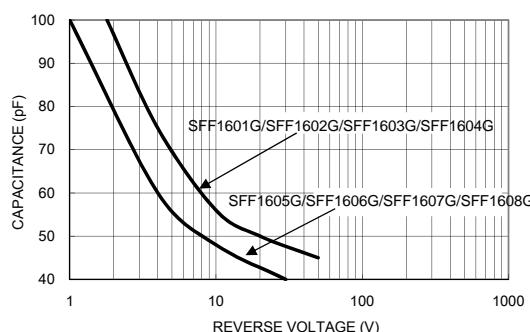


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

